

#

12 Sep 2017

① For amplification, transistor has to be in Forward Active region

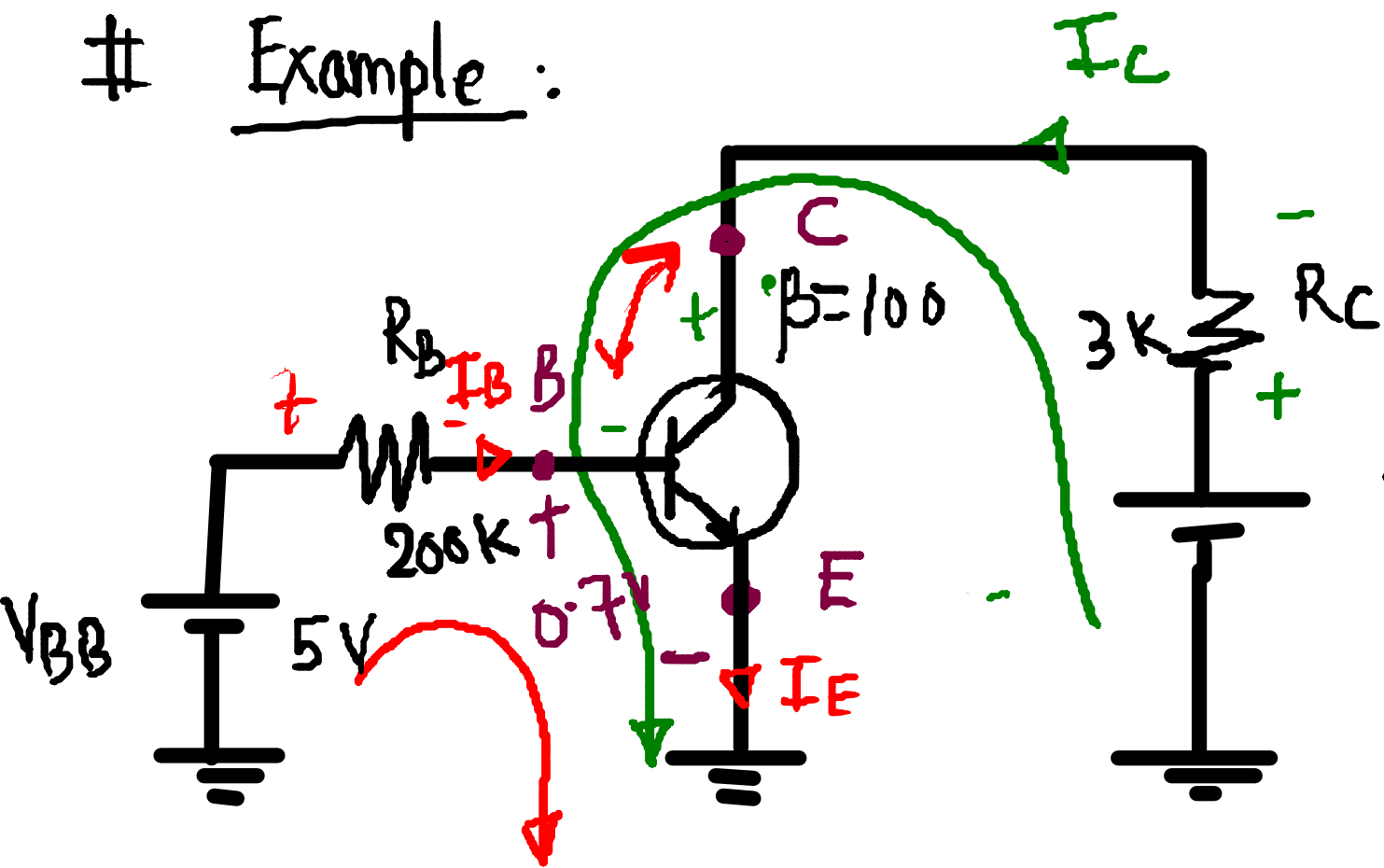
I_E : FB

I_C : RB

② Appropriate biasing has to be applied to the transistor.

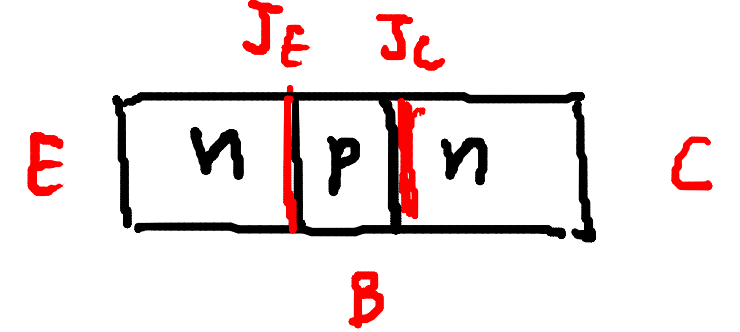
↓
dc. voltage

Example :



Step ①:

$$V_{BE} = 0.7V$$



$$V_{BE} \geq 0.7$$

$$V_{CB} \geq 0$$

$$V_{CB} = V_C - V_B$$

$$V_{BB} - I_B R_B - 0.7 = 0$$

$$I_B = \frac{V_{BB} - V_{BE}}{R_B}$$

$$I_B = 0.0215 \text{ mA}$$

Emitter Junction is Forward Bias

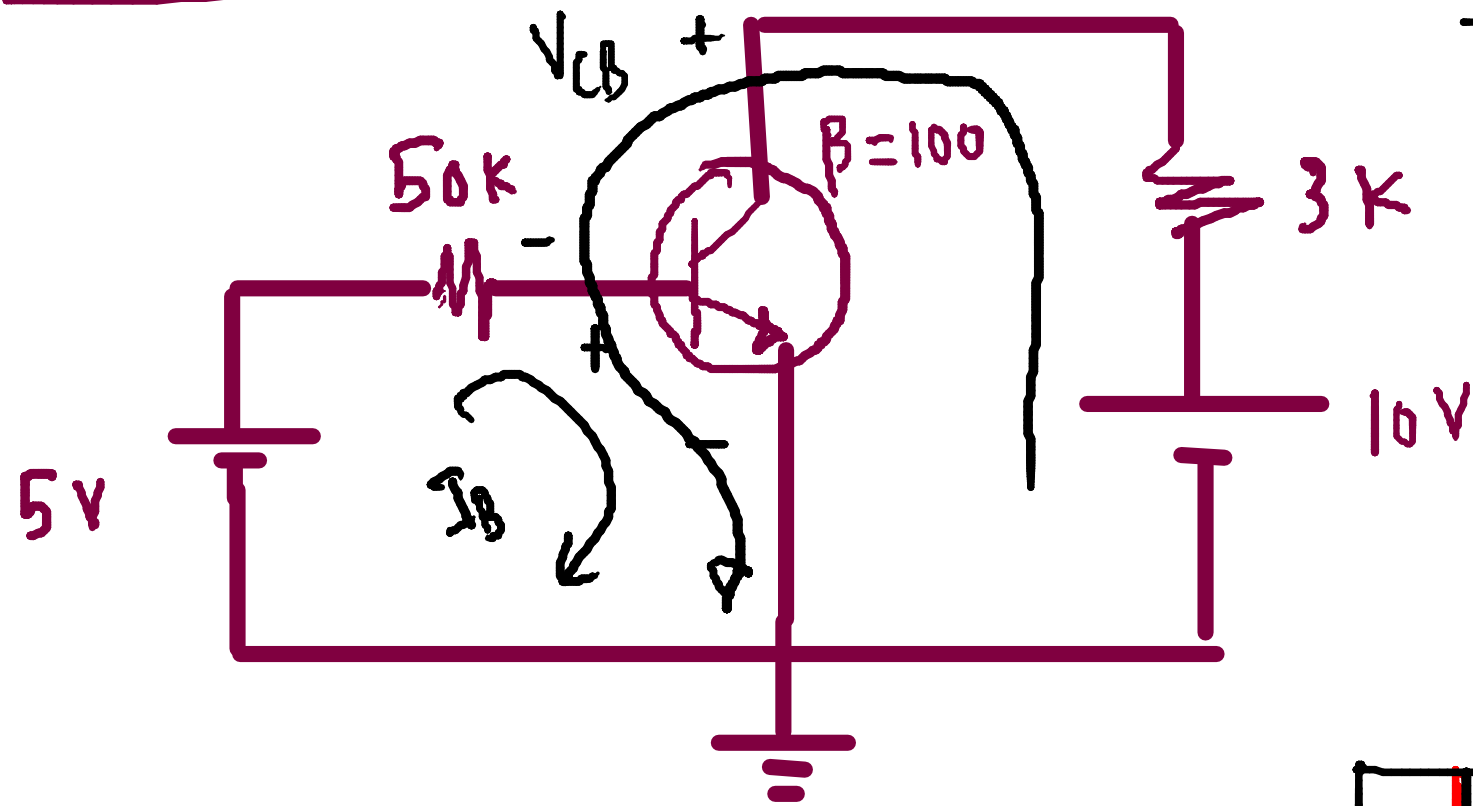
Step ②: $V_{CC} - I_C R_C - V_{CB} - V_{BE} = 0$

$$V_{CB} = V_{CC} - (\beta I_B) R_C - V_{BE}$$

$$V_{CB} = 2.85V$$

J_C is

Example



Step(1):

$$I_B = 0.086 \text{ mA}$$

$$I_C = 8.6 \text{ mA}$$

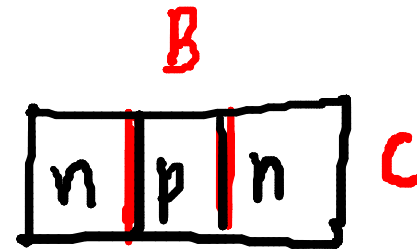
I_E is **FB**

Step(2)

kvl @ I_C

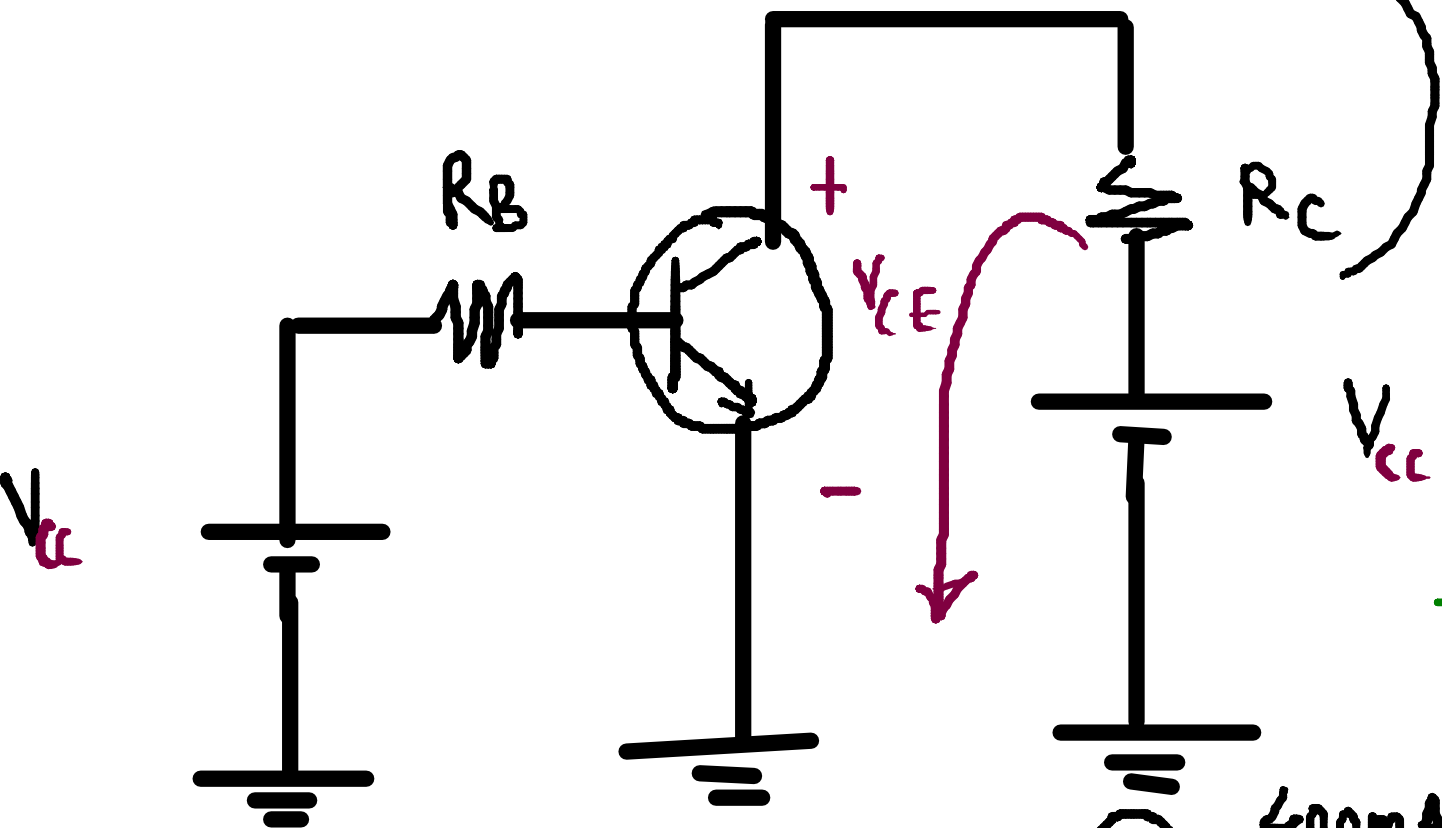
$$V_{CB} = -16.5$$

I_C is **FB**



\therefore Transistor is in **Saturation.**

Fixed-bias Configuration :



$$V_{CE} = V_{CC} - I_C R_C$$

\downarrow x \downarrow y

